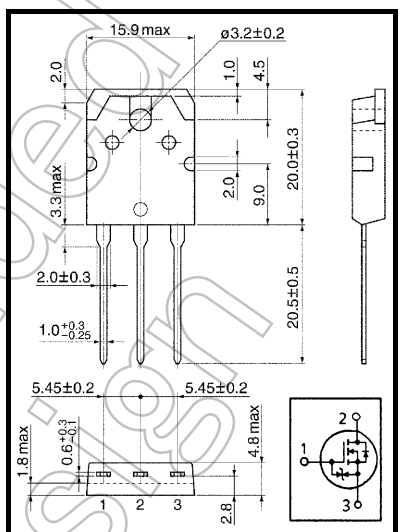
TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (π−MOSIII)

# 2SK2607

Chopper Regulator, DC−DC Converter and Moter Drive Applications

- Low drain−source ON-resistance : $R_{DS\ (ON)}$ = 1.0 Ω (typ.)
- High forward transfer admittance : $|Y_{fs}|$ = 7.0 S (typ.)
- Low leakage current : $I_{DSS}$ = 100 μA (max) ($V_{DS}$ = 640 V)
- Enhancement mode : $V_{th}$ = 2.0 to 4.0 V ($V_{DS}$ = 10 V, $I_D$ = 1 mA)

Unit: mm




1. GATE
2. DRAIN (HEAT SINK)
3. SOURCE

| | |
|---|---|
| JEDEC | — |
| JEITA | SC-65 |
| TOSHIBA | 2-16C1B |

Weight: 4.6 g (typ.)

## Absolute Maximum Ratings (Ta = 25°C)

| Characteristics | | Symbol | Rating | Unit |
|---|---|---|---|---|
| Drain−source voltage | | $V_{DSS}$ | 800 | V |
| Drain−gate voltage ($R_{GS}$ = 20 kΩ) | | $V_{DGR}$ | 800 | V |
| Gate−source voltage | | $V_{GSS}$ | ±30 | V |
| Drain current | DC (Note 1) | $I_D$ | 9 | A |
| | Pulse (Note 1) | $I_{DP}$ | 27 | |
| Drain power dissipation (Tc = 25°C) | | $P_D$ | 150 | W |
| Single pulse avalanche energy (Note 2) | | $E_{AS}$ | 778 | mJ |
| Avalanche current | | $I_{AR}$ | 9 | A |
| Repetitive avalanche energy (Note 3) | | $E_{AR}$ | 15 | mJ |
| Channel temperature | | $T_{ch}$ | 150 | °C |
| Storage temperature range | | $T_{stg}$ | −55 to 150 | °C |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook (“Handling Precautions”/“Derating Concept and Methods”) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

## Thermal Characteristics

| Characteristic | Symbol | Max | Unit |
|---|---|---|---|
| Thermal resistance, channel to case | $R_{th\ (ch-c)}$ | 0.833 | °C / W |
| Thermal resistance, channel to ambient | $R_{th\ (ch-a)}$ | 50 | °C / W |

Note 1: Ensure that the channel temperature does not exceed 150°C.

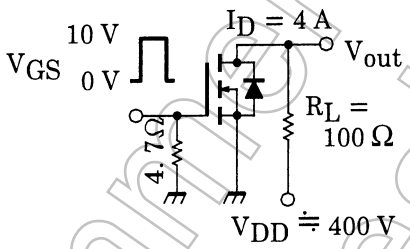
Note 2: $V_{DD}$ = 90 V, $T_{ch}$ = 25°C (initial), L = 17.4 mH, $R_G$ = 25 Ω, $I_{AR}$ = 9 A

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device.
Please handle with caution.

Start of commercial production
1995-12

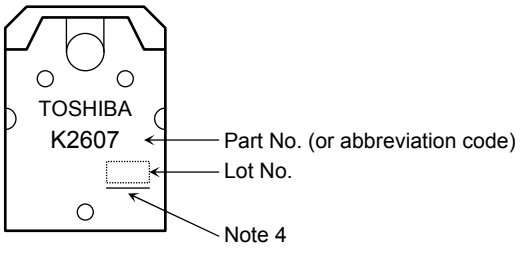
## Electrical Characteristics (Ta = 25°C)

| Characteristics | | Symbol | Test Condition | Min | Typ. | Max | Unit |
|---|---|---|---|---|---|---|---|
| Gate leakage current | | $I_{GSS}$ | $V_{GS}$ = ±30 V, $V_{DS}$ = 0 V | — | — | ±10 | μA |
| Gate−source breakdown voltage | | $V_{(BR)\ GSS}$ | $I_G$ = ±10 μA, $V_{DS}$ = 0 V | ±30 | — | — | V |
| Drain cut−off current | | $I_{DSS}$ | $V_{DS}$ = 640 V, $V_{GS}$ = 0 V | — | — | 100 | μA |
| Drain−source breakdown voltage | | $V_{(BR)\ DSS}$ | $I_D$ = 10 mA, $V_{GS}$ = 0 V | 800 | — | — | V |
| Gate threshold voltage | | $V_{th}$ | $V_{DS}$ = 10 V, $I_D$ = 1 mA | 2.0 | — | 4.0 | V |
| Drain−source ON-resistance | | $R_{DS\ (ON)}$ | $V_{GS}$ = 10 V, $I_D$ = 4 A, | — | 1.0 | 1.2 | Ω |
| Forward transfer admittance | | $\|Y_{fs}\|$ | $V_{DS}$ = 15 V, $I_D$ = 4 A | 3.0 | 7.0 | — | S |
| Input capacitance | | $C_{iss}$ | $V_{DS}$ = 25 V, $V_{GS}$ = 0 V, f = 1 MHz | — | 2160 | — | pF |
| Reverse transfer capacitance | | $C_{rss}$ | | — | 45 | — | |
| Output capacitance | | $C_{oss}$ | | — | 200 | — | |
| Switching time | Rise time | $t_r$ |   | — | 25 | — | ns |
| | Turn−on time | $t_{on}$ | | — | 60 | — | |
| | Fall time | $t_f$ | | — | 25 | — | |
| | Turn−off time | $t_{off}$ | | — | 110 | — | |
| Total gate charge (gate−source plus gate−drain) | | $Q_g$ | $V_{DD}$ ≈ 400 V, $V_{GS}$ = 10 V, $I_D$ = 9 A | — | 68 | — | nC |
| Gate−source charge | | $Q_{gs}$ | | — | 38 | — | |
| Gate−drain (“miller”) Charge | | $Q_{gd}$ | | — | 30 | — | |

## Source−Drain Ratings and Characteristics (Ta = 25°C)

| Characteristics | Symbol | Test Condition | Min | Typ. | Max | Unit |
|---|---|---|---|---|---|---|
| Continuous drain reverse current (Note 1) | $I_{DR}$ | — | — | — | 9 | A |
| Pulse drain reverse current (Note 1) | $I_{DRP}$ | — | — | — | 27 | A |
| Forward voltage (diode) | $V_{DSF}$ | $I_{DR}$ = 9 A, $V_{GS}$ = 0 V | — | — | −1.9 | V |
| Reverse recovery time | $t_{rr}$ | $I_{DR}$ = 9 A, $V_{GS}$ = 0 V, $dI_{DR}$ / dt = 100 A / μs | — | 1000 | — | ns |
| Reverse recovery charge | $Q_{rr}$ | | — | 12 | — | μC |

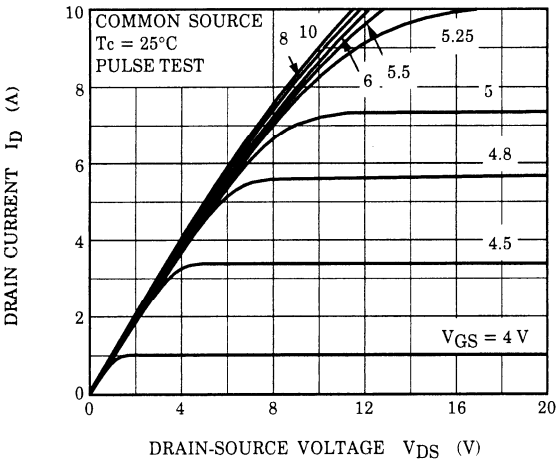
## Marking



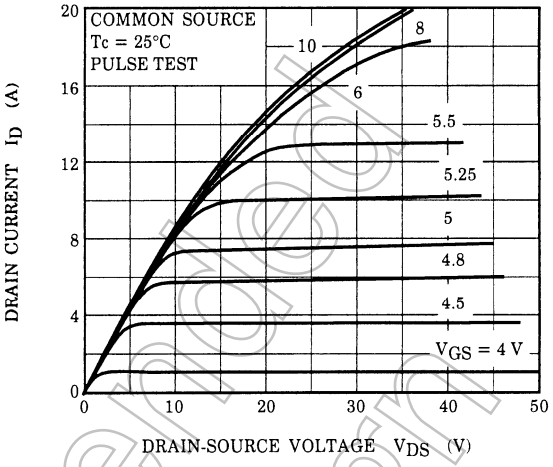

Note 4: A line under a Lot No. identifies the indication of product Labels.
Not underlined: [[Pb]]/INCLUDES > MCV
Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

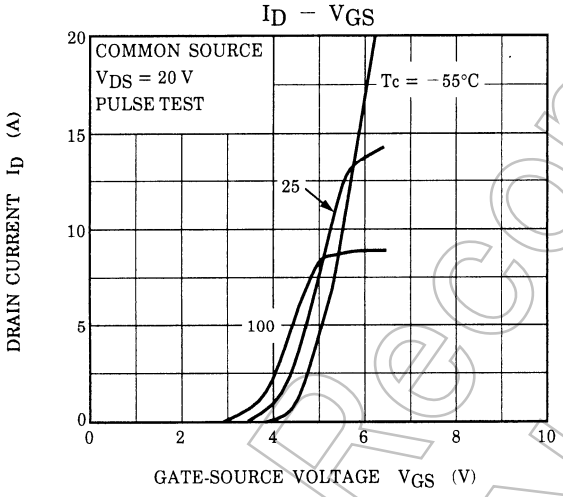
$I_D - V_{DS}$



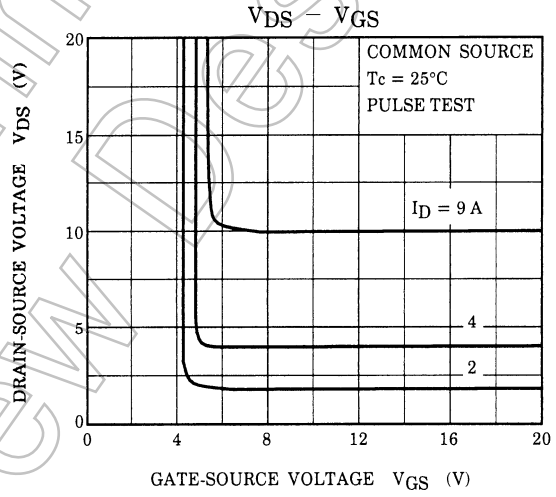

$I_D - V_{DS}$



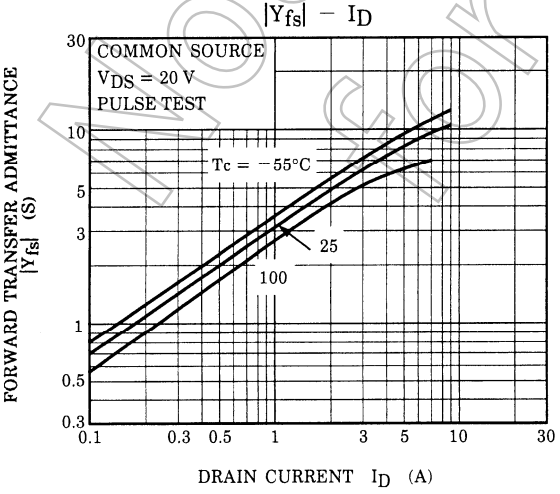

$I_D - V_{GS}$



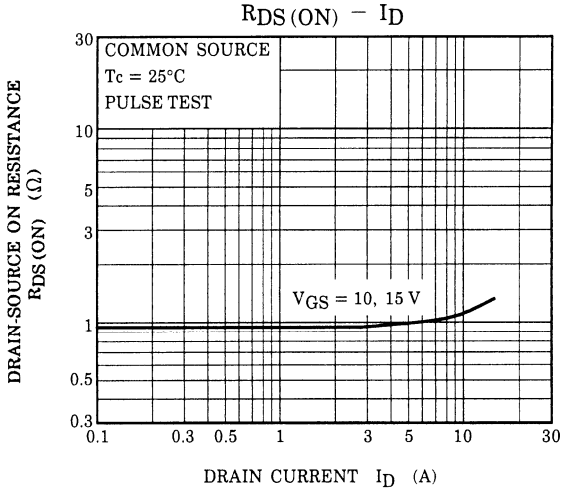

$V_{DS} - V_{GS}$



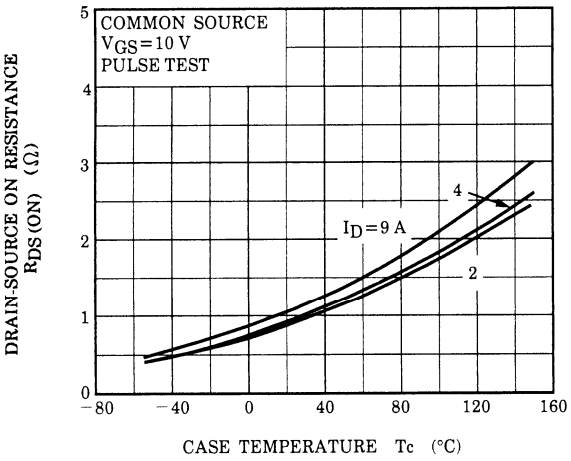

$|Y_{fs}| - I_D$



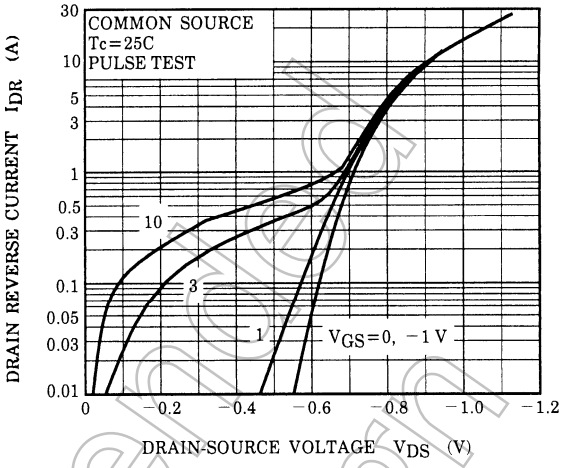

$R_{DS\,(ON)} - I_D$



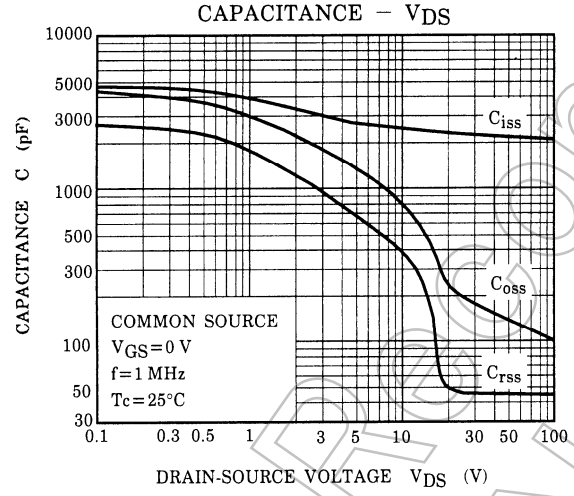
$R_{DS\,(ON)}$ – Tc



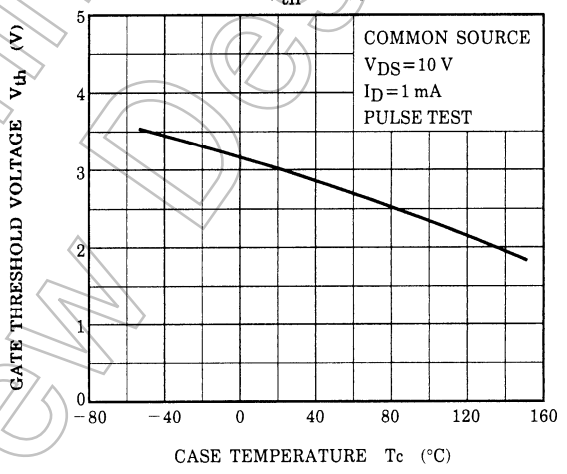

$I_{DR}$ – $V_{DS}$



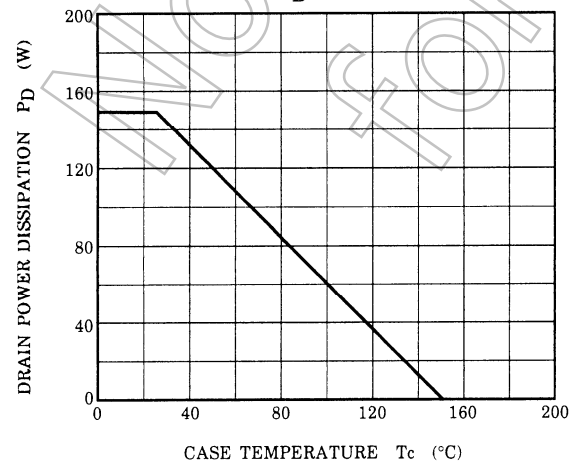

CAPACITANCE – $V_{DS}$



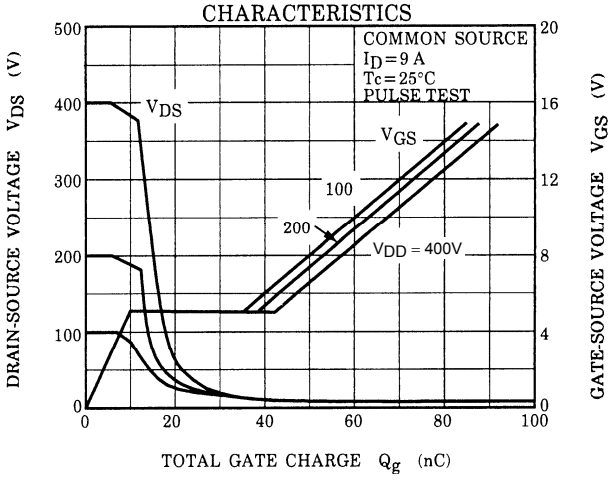

$V_{th}$ – Tc



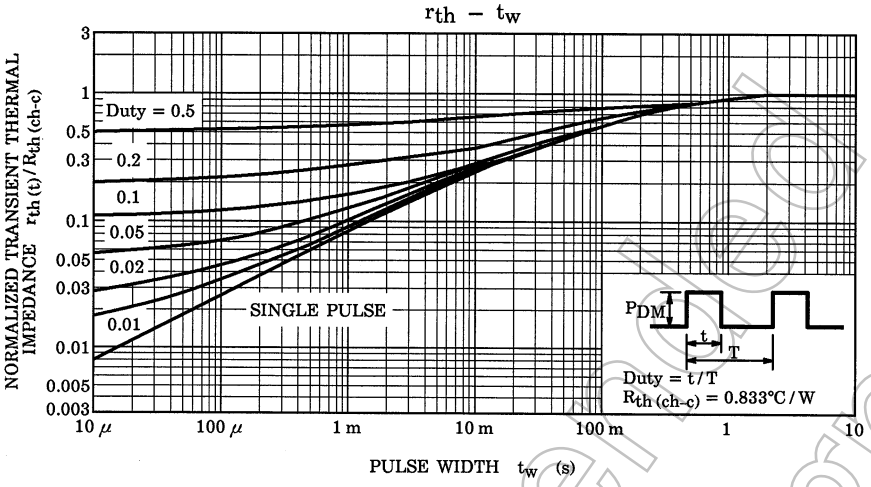

$P_D$ – Tc



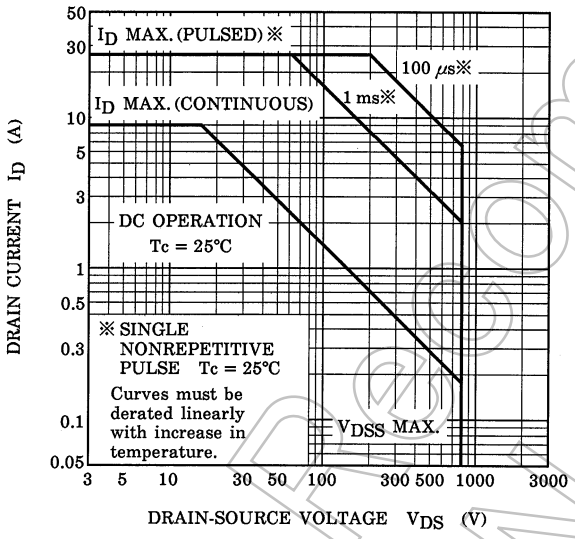

DYNAMIC INPUT / OUTPUT CHARACTERISTICS



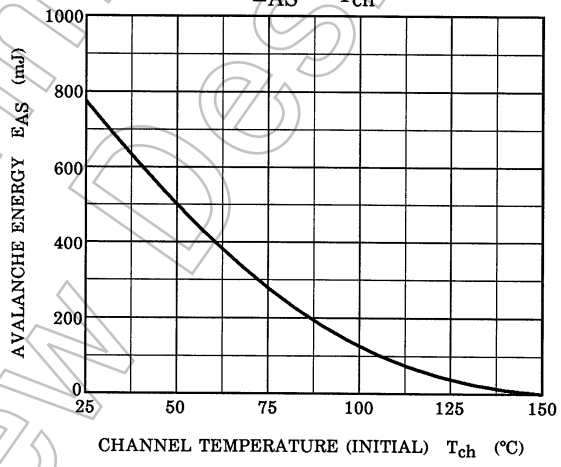
$r_{th}$ – $t_w$

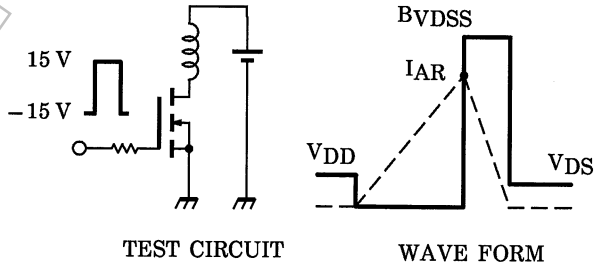



SAFE OPERATING AREA




$E_{AS}$ – $T_{ch}$




$R_G = 25\ \Omega$
$V_{DD} = 90$ V, L = 17.4 mH

$$E_{AS} = \frac{1}{2} \cdot L \cdot I^2 \cdot \left( \frac{B_{VDSS}}{B_{VDSS} - V_{DD}} \right)$$

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